



SPN75T15A

N-Channel Enhancement Mode MOSFET

DESCRIPTION

The SPN75T15A is the N-Channel enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology. The SPN75T15A has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{DS(ON)}$ and fast switching speed.

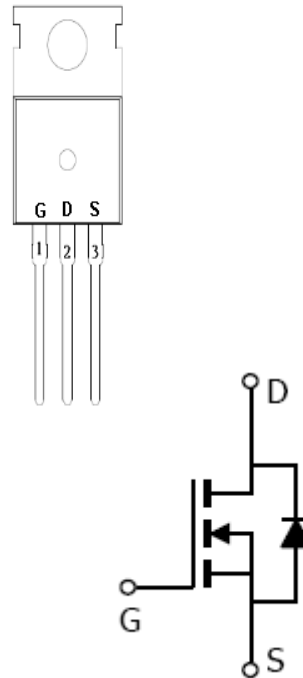
FEATURES

- ◆ 150V/91A, $R_{DS(ON)}=11.5\text{ m}\Omega@V_{GS}=10\text{V}$
- ◆ Super high density cell design for extremely low $R_{DS(ON)}$
- ◆ Exceptional on-resistance and maximum DC current capability
- ◆ TO-220-3L package design

APPLICATIONS

- DC/DC Converter
- Load Switch
- SMPS Secondary Side Synchronous Rectifier
- Motor Control
- Power Tool

PIN CONFIGURATION(TO-220-3L)



PART MARKING



A : Lot Code
B : Date Code



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PIN DESCRIPTION (TO-220-3L)

Pin	Symbol	Description
1	G	Gate
2	D	Drain
3	S	Source

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN75T15AT220TGB	TO-220-3L	SPN75T15A

※ SPN75T15AT220TGB : Tube ; Pb – Free ; Halogen – Free

ABSOLUTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter	Symbol	Typical	Unit	
Drain-Source Voltage	V _{DSS}	150	V	
Gate – Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Silicon Limited)	I _D	T _C =25°C	91	A
		T _C =100°C	64	
Pulsed Drain Current	I _{DM}	300	A	
Single Pulse Avalanche Energy (T _C =25°C , L=0.4mH.)	E _{AS}	320	mJ	
Power Dissipation (TO-220-3L)	P _D	104	W	
Operating Junction Temperature	T _J	-55/150	°C	
Storage Temperature Range	T _{STG}	-55/150	°C	
Thermal Resistance-Junction to Case (TO-220-3L)	R _{θJC}	1.2	°C/W	

Note :

The maximum current rating is package limited at 120A for TO-220-3L



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ELECTRICAL CHARACTERISTICS

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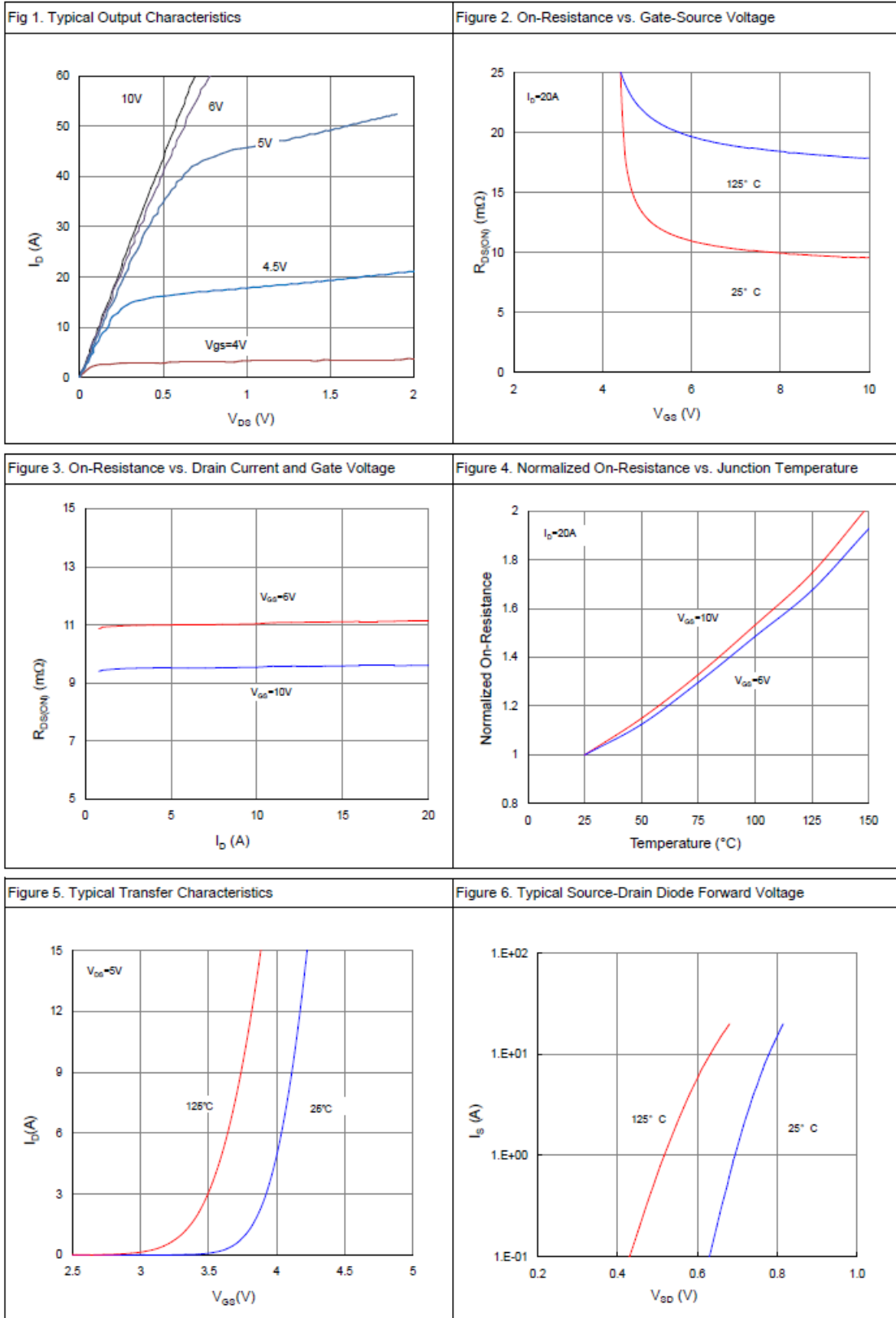
Parameter	Symbol	Conditions	Min.	Typ	Max.	Unit
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	150			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2.0		4.0	V
Gate Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=120V, V_{GS}=0V$ $T_J=25^\circ C$,			1	uA
		$V_{DS}=120V, V_{GS}=0V$, $T_J=100^\circ C$			100	
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=20A$		9.6	11.5	mΩ
Forward Transconductance	g_{fs}	$V_{DS}=5V, I_D=20A$		65		S
Gate resistance	R_g	$V_{DS}=0V, V_{GS}=0V$ $f=1MHz$		2.8		Ω
Diode Forward Voltage	V_{SD}	$I_S=20A, V_{GS}=0V$		0.9	1.2	V
Dynamic						
Total Gate Charge	$Q_g(10V)$	$V_{DS}=75V, V_{GS}=10V$ $I_D=20A$		42		nC
Gate-Source Charge	Q_{gs}			14		
Gate-Drain Charge	Q_{gd}			7		
Input Capacitance	C_{iss}	$V_{DS}=75V, V_{GS}=0V$ $f=1MHz$		3365		pF
Output Capacitance	C_{oss}			239		
Reverse Transfer Capacitance	C_{rss}			6.5		
Turn-On Time	$t_{d(on)}$	$V_{DD}=75V$, $I_D=20A, V_{GS}=10V$ $R_G=10\Omega$		17		nS
	t_r			8		
Turn-Off Time	$t_{d(off)}$			26		
	t_f			10		



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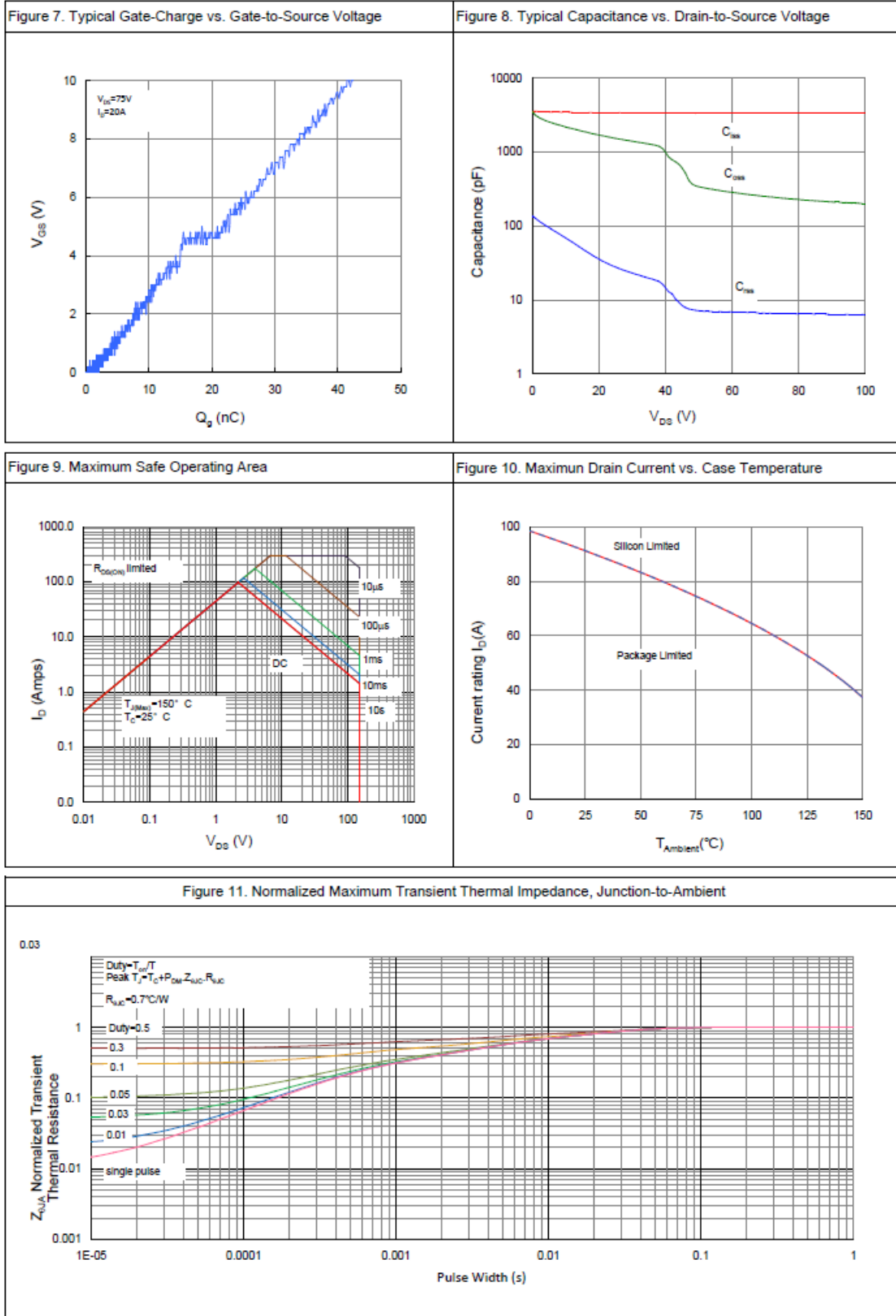
TYPICAL CHARACTERISTICS





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TYPICAL CHARACTERISTICS





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